innodisk

Total Solution For Industrial Flash Storage

mSATA

3TG6-P Series

Customer: _____

Customer Part Number: _____

Innodisk Part Number: _____

Innodisk Model Name: _____

Date: _____

Innodisk Approver	Customer Approver

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Revision History

Revision	Description	Date
Preliminary	First Released	July, 2018
1.0	Officially released	Sep. 2018
1.1	Update Power Consumption	Apr. 2019
1.2	Update Performance Update Trim Function Description Update RoHS Declaration of Conformity	Apr. 2019
1.3	Add AES Information Update Power Consumption	Aug., 2019
1.4	Update Mechanical Drawing for 1TB Model	Aug., 2019
1.5	Update Thermal Management Information	Nov., 2019
1.6	Correct Part Number	Jan., 2020

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1. Product Overview

1.1 Introduction of Innodisk mSATA 3TG6-P

Innodisk mSATA 3TG6-P products provide high capacity flash memory Solid State Drive (SSD) that electrically complies with Serial ATA (SATA) standard. It supports SATA III standard (6.0GHz) with high performance. Innodisk mSATA 3TG6-P is designed for industrial field, and supports several standard features, including TRIM, NCQ, and S.M.A.R.T. The SSD have good performance, no latency time and small seek time. It effectively reduces the booting time of operation system and the power consumption is less than hard disk drive (HDD).

1.2 Product View and Models

Innodisk mSATA 3TG6-P is available in follow capacities:

mSATA 3TG6-P 128GB mSATA 3TG6-P 256GB

mSATA 3TG6-P 512GB mSATA 3TG6-P 1TB

Figure 1: Innodisk mSATA 3TG6-P

(Write protect is Optional)

1.3 SATA Interface

Innodisk mSATA 3TG6-P supports SATA III interface, and backward compliant with SATA I and SATA II.

2. Product Specifications

2.1 Capacity and Device Parameters

mSATA 3TG6-P device parameters are shown in Table 1.

Table 1: Device parameters

Capacity	LBA	Cylinders	Heads	Sectors	User Capacity(MB)
128GB	214906608	16383	16	63	104934
256GB	468862128	16383	16	63	228936
512GB	937703088	16383	16	63	457862
1TB	1875385008	16383	16	63	915715

2.2 Performance

Burst Transfer Rate: 6.0Gbps

Table 2: Performance

Capacity	128GB	256GB	512GB	1TB
Sequential* Read (max.)	560	560	560	520
Sequential Write (max.)	135	290	520	450
4KB Random Read (QD32)	41000	73000	87000	50000
4KB Random Write (QD32)	35000	54000	75000	44000

Note: * Sequential performance based on CrystalDiskMark 5.1.2 with file size 1000MB

** Random performance based on IOmeter with Queue Depth 32

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 3: Innodisk mSATA 3TG6-P Power Requirement

Item	Symbol	Rating	Unit
Input voltage	V_{IN}	+3.3 DC +- 5%	V

2.3.2 Power Consumption

Table 4: Power Consumption

Mode	Power Consumption (mA)			
	128GB	256GB	512GB	1TB
Read	503	514	591	634
Write	402	561	797	845
Idle	224	224	233	250
Peak	746	806	857	845

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 5: Temperature range for mSATA 3TG6-P

Temperature	Range
Operating	Standard Grade: 0°C to +70°C
	Industrial Grade:-40°C to +85°C
Storage	-55°C to +95°C

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for mSATA 3TG6-P

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 68-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 68-2-27

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various mSATA 3TG6-P configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate**: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF)**: A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 7: mSATA 3TG6-P MTBF

Product	Condition	MTBF (Hours)
Innodisk mSATA 3TG6-P	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

mSATA 3TG6-P conforms to CE and FCC requirements.

2.6 RoHS Compliance

mSATA 3TG6-P is fully compliant with RoHS directive.

2.7 Reliability

Parameter	Value	
Read Cycles	Unlimited Read Cycles	
Flash endurance	3,000 P/E cycles	
Wear-Leveling Algorithm	Support	
Bad Blocks Management	Support	
Error Correct Code	Support	
TBW* (Total Bytes Written) Unit:TB		
Capacity	**Sequential workload**	**Client workload**
128GB	340.9	150
256GB	681.8	300
512GB	1364	600
1TB	2663	1172

*Note:

1. Sequential: Mainly sequential write, tested by Vdbench.
2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)
3. Based on out-of-box performance.

2.8 Transfer Mode

mSATA 3TG6-P support following transfer mode:

Serial ATA III 6.0Gbps

Serial ATA II 3.0Gbps

Serial ATA I 1.5Gbps

2.9 Pin Assignment

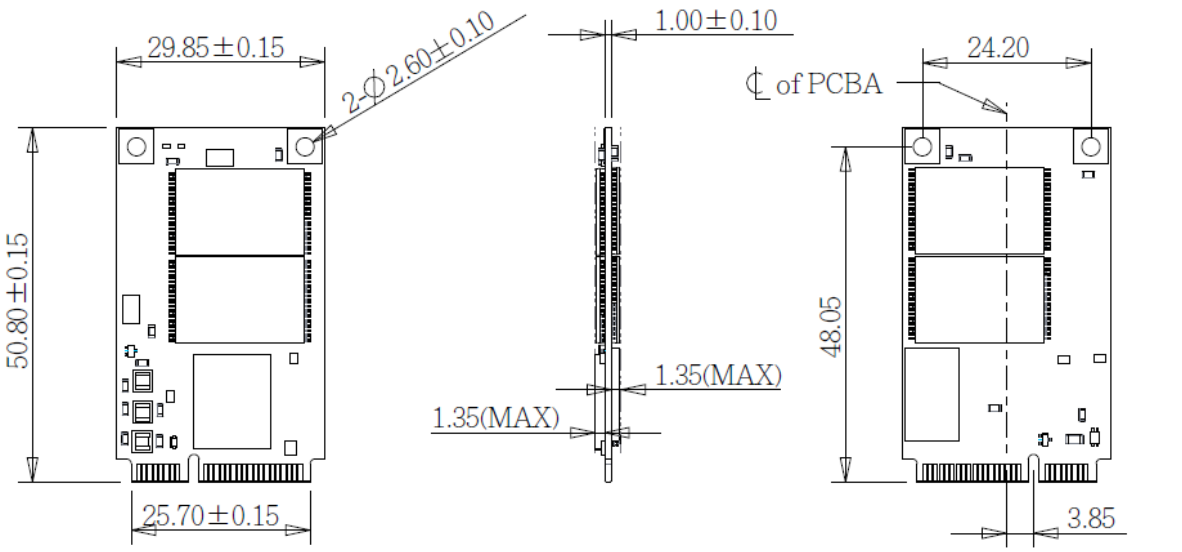
Innodisk mSATA 3TG6-P uses a standard SATA pin-out. See Table 8 for mSATA 3TG6-P pin assignment.

Table 8: Innodisk mSATA 3TG6-P Pin Assignment

Signal Name	Pin #	Pin #	Signal Name
GND	51	52	+3.3V
DAS	49	50	GND
NC	47	48	NC
NC	45	46	NC
NC	43	44	DEVSLP
+3.3V	41	42	NC
+3.3V	39	40	GND
GND	37	38	NC
GND	35	36	NC
RX+	33	34	GND
RX-	31	32	NC
GND	29	30	NC
GND	27	28	NC
TX-	25	26	GND
TX+	23	24	+3.3V
GND	21	22	NC
NC	19	20	NC
NC	17	18	GND
GND	15	16	NC
NC	13	14	NC
NC	11	12	NC
GND	9	10	NC

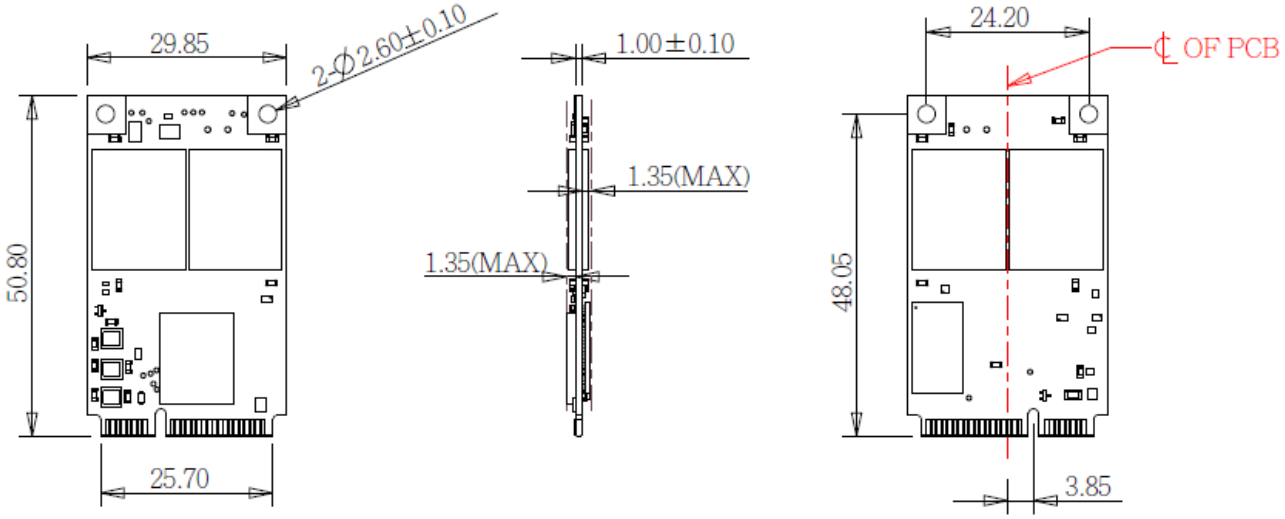
NC	7	8	NC
NC	5	6	NC
NC	3	4	GND
NC	1	2	+3.3V

2.10 Mechanical Dimensions



TOLERENCE: ±0.15mm
UNIT: mm

TSOP Models: 128GB~512GB



TOLERANCE:±0.15
UNIT:mm

BGA Model: 1TB

2.11 Assembly Weight

An Innodisk mSATA 3TG6-P within 3D NAND flash ICs, 256GB's weight is 8 grams approx.

2.12 Seek Time

Innodisk mSATA 3TG6-P is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 NAND Flash Memory

Innodisk mSATA 3TG6-P uses 3D TLC NAND flash memory, with 3,000 programs & erases cycles, which is non-volatility, high reliability and high-speed memory storage.

2.14 Thermal Management

Innodisk mSATA 3TG6-P adopts optimized thermal management. In extreme temperature, disk will perform thermal throttling to ensure overall device stability. Disabling thermal throttling function may improve the performance but also expose device potential issues while operating under extreme environment conditions.

3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk mSATA 3TG6-P from the system level, including the major hardware blocks.

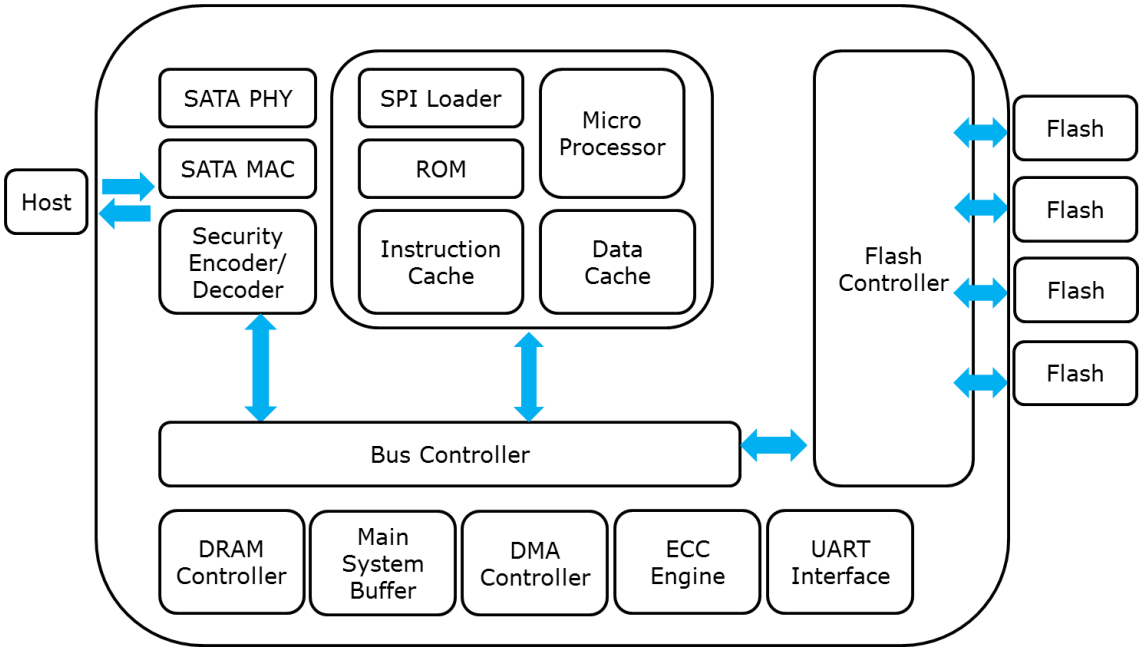


Figure 2: Innodisk mSATA 3TG6-P Block Diagram

Innodisk mSATA 3TG6-P integrates a SATA III controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard ATA protocol. Communication with the flash device(s) occurs through the flash interface.

3.2 SATA Controller

Innodisk mSATA 3TG6-P is designed with 88SS1080, a SATA III 6.0Gbps controller, The Serial ATA physical, link and transport layers are compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps/3.0Gbps/6.0Gbps data rate). The controller has 4 channels for flash interface.

3.3 Error Detection and Correction

Innodisk mSATA 3TG6-P is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the ***erase cycle limit*** or ***write endurance limit*** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk mSATA 3TG6-P uses a static wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 iData Guard

Innodisk's iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

3.8 iPower Guard

iPower Guard technology is a set of preventive measures that protect the SSD in an unstable power supply environment. This comprehensive package comprises safeguards for startup and shutdown to maintain device performance and ensure data integrity.

3.9 AES Function

In order to complete the physical security layer of protection, encryption needs to be paired with an ATA user password by ATA security command. After setting the authorized key by ATA security command, every time when you power on the system with SSD encrypted, you will be requested for a password to access the SSD. If the password is correct, the SSD will run well; if not, then you will not be able to access the SSD then.

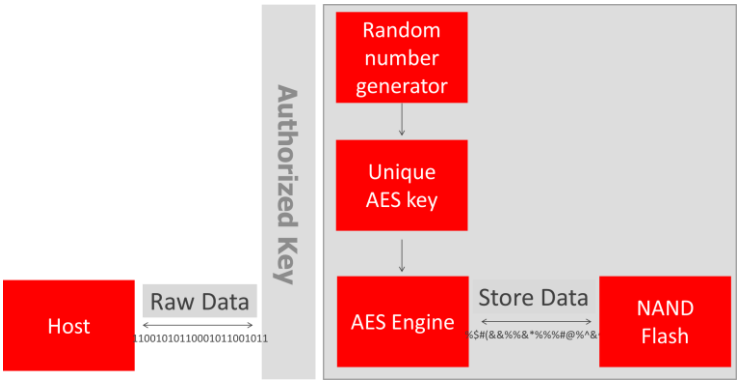


Figure 3: Innodisk mSATA 3TG6-P AES flow chart

3.9.1 Encrypted Key Management

Innodisk 3TG6-P SSD includes two methods of key management to apply to different applications. The first is a standard approach that allows the firmware to generate a random number and a unique key when it leaves the factory. This method ensures that the user can easily apply the SSD with the data encrypted key. Another approach is to meet unique customer requirements with an encrypted key generated by an SSD from the SATA interface host. The SSD must keep the encrypted key value when receiving the reset commands. This method works best for the SSD as a removable device in different systems. Innodisk provides the test tool to execute the AES hardware encryption. This user-friendly tool, developed by Innodisk Corporation, allows the customer to use/test encryption functions.

3.9.2 Authorized Key Management

In order to complete the physical security layer of protection, encryption needs to be bundled with an ATA user password provided by an ATA Security command. Unlike the AES key, the authorized key must be set by the user via the BIOS configuration. Every time you power on the system with SSD encryption, a password request prompt is sent to access the SSD. If the password is correct, the SSD will run well; if not, you will not be able to access the SSD.

Command	Command Code
SECURITY SET PASSWORD	0XF1
SECURITY UNLOCK	0XF2
SECURITY ERASE PREPARE	0XF3
SECURITY ERASE UNIT	0XF4
SECURITY FREEZE LOCK	0XF5
SECURITY DISABLE PASSWORD	0XF6

4. Installation Requirements

4.1 mSATA 3TG6-P Pin Directions

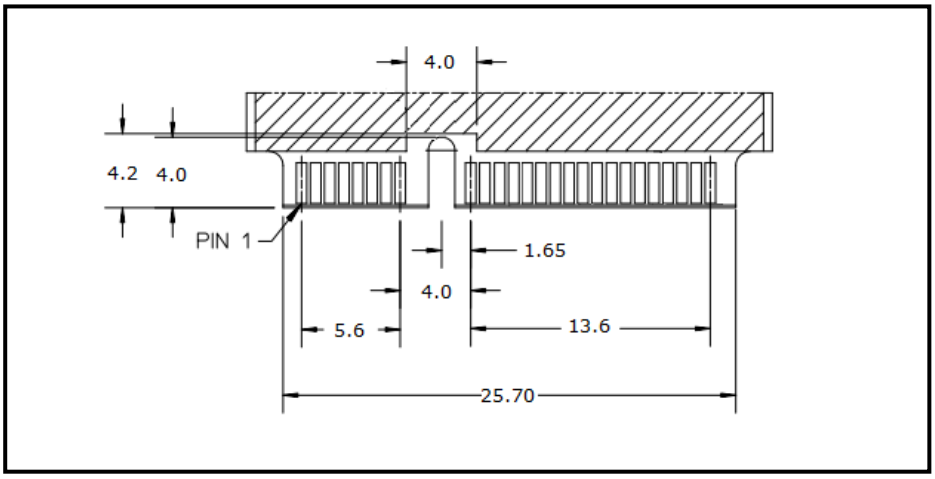


Figure 4: Signal Segment and Power Segment

4.2 Electrical Connections for mSATA 3TG6-P

A Serial ATA device may be either directly connected to a host or connected to a host through an adaptor card. The SATA interface has a separate connector for the power supply. Please refer to the pin description for further details.

4.3 Device Drive

No additional device drives are required. Innodisk mSATA 3TG6-P can be configured as a boot device.

5. SMART Feature Set

Innodisk 3TG6-P series support the SMART command set and defines some vendor-specific data to report SMART attributes of SSD.

Value	Command
D0h	Read Data
D1h	Read Attribute Threshold
D2h	Enable/Disable Autosave
D3h	Save Attribute Values
D4h	Execute OFF-LINE Immediate
D5h	Read Log
D6h	Return Status
D8h	Enable SMART Operations
D9h	Disable SMART Operations
DAh	Return Status

5.1 SMART Attributes

Innodisk 3TG6-P series SMART data attributes are listed in following table.

Attribute ID (hex)	**Raw Attribute Value**							**Attribute Name**
1 (01h)	MSB	00	00	00	00	00	00	Raw Read Error Rate
5 (05h)	LSB	MSB	00	00	00	00	00	Reallocated Sector Count
9 (09h)	LSB			MSB	00	00	00	Power-on Hours
12 (0Ch)	LSB			MSB	00	00	00	Power Cycle Count
160 (A0h)	LSB			MSB	00	00	00	Uncorrectable sector count when read/write
161 (A1h)	LSB	MSB	00	00	00	00	00	Number of valid spare block
163 (A3h)	LSB	MSB	00	00	00	00	00	Number of initial invalid block
164 (A4h)	LSB	MSB	00	00	00	00	00	Total erase count
165 (A5h)	LSB			MSB	00	00	00	Maximum erase count
166 (A6h)	LSB			MSB	00	00	00	Minimum erase count
167 (A7h)	LSB			MSB	00	00	00	Average erase count
168 (A8h)	LSB			MSB	00	00	00	Max erase count of spec
169 (A9h)	LSB			MSB	00	00	00	Remain Life (percentage)

175 (AFh)	LSB			MSB	00	00	00	Program fail count in worst die
176 (B0h)	LSB			MSB	00	00	00	Erase fail count in worst die
177 (B1h)	LSB			MSB	00	00	00	Total wear level count
178 (B2h)	LSB	MSB	00	00	00	00	00	Runtime invalid block count
181 (B5h)	LSB			MSB	00	00	00	Total program fail count
182 (B6h)	LSB	MSB	00	00	00	00	00	Total erase fail count
187 (BBh)	LSB			MSB	00	00	00	Uncorrectable error count
192 (C0h)	LSB	MSB	00	00	00	00	00	Power-Off Retract Count
194 (C2h)	MSB	00	00	00	00	00	00	Controlled temperature
195 (C3h)	LSB			MSB	00	00	00	Hardware ECC recovered
196 (C4h)	LSB			MSB	00	00	00	Reallocation event count
198 (C6h)	LSB			MSB	00	00	00	Uncorrectable error count off-line
199 (C7h)	LSB	MSB	00	00	00	00	00	UltraDMA CRC error count
225 (E1h)	LSB						MSB	Total LBAs written (each write unit = 32MB)
232 (E8h)	LSB	MSB	00	00	00	00	00	Available reserved space
241 (F1h)	LSB						MSB	Total LBAs written (each write unit = 32MB)
242 (F2h)	LSB						MSB	Total LBAs read (each write unit = 32MB)

6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
	D	**G**	**M**	**S**	**R**	**-**	**A**	**2**	**8**	**M**	**7**	**1**	**E**	**C**	**1**	**Q**	**F**	**-**	**X**	**X**	**X**
Description	Disk	mSATA					Capacity			Category			Flash mode	Operation Temp.	Internal Control	CH.	Flash		Customized Code		

Definition	
Code 1st (Disk)	**Code 13th (Flash mode)**
D : Disk	E: 64 layers 3D TLC
Code 2nd ~ 5th (Form Factor)	**Code 14th (Operation Temperature)**
GMSR: mSATA regular	C: Standard Grade (0℃~ +70℃)
	W: Industrial Grade (-40℃~ +85℃)
Code 7th ~9th (Capacity)	**Code 15th (Internal control)**
A28: 128GB	1/A: PCB version
B56: 256GB	**Code 16th (Channel of data transfer)**
C12:512GB	S: Single Channel
01T: 1TB	D: Duo Channels
	Q: Quad Channels
Code 10th ~12th (Series)	**Code 17th (Flash Type)**
M71: mSATA 3TG6-P	F: Toshiba 3D TLC
	Code 20th ~21th (Customized code)

Appendix

宜鼎國際股份有限公司
Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

RoHS 自我宣告書 (RoHS Declaration of Conformity)

Manufacturer Product: All Innodisk EP products

一、 宜鼎國際股份有限公司（以下稱本公司）特此保證售予貴公司之所有產品，皆符合歐盟 2011/65/EU 及(EU) 2015/863 關於 RoHS 之規範要求。

Innodisk Corporation declares that all products sold to the company, are complied with European Union RoHS Directive (2011/65/EU) and (EU) 2015/863 requirement.

二、 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。

Innodisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

Name of hazardous substance	Limited of RoHS ppm (mg/kg)
鉛 (Pb)	< 1000 ppm
汞 (Hg)	< 1000 ppm
鎘 (Cd)	< 100 ppm
六價鉻 (Cr 6+)	< 1000 ppm
多溴聯苯 (PBBs)	< 1000 ppm
多溴二苯醚 (PBDEs)	< 1000 ppm
鄰苯二甲酸二(2-乙基己基)酯 (DEHP)	< 1000 ppm
鄰苯二甲酸丁酯苯甲酯 (BBP)	< 1000 ppm
鄰苯二甲酸二丁酯 (DBP)	< 1000 ppm
鄰苯二甲酸二異丁酯 (DIBP)	< 1000 ppm

立 保 證 書 人 (Guarantor)

Company name 公司名稱： Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人： Randy Chien 簡川勝

Company Representative Title 公司代表人職稱： Chairman 董事長

Date 日期： 2018 / 07 / 01

宜鼎國際股份有限公司
Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

REACH Declaration of Conformity

Manufacturer Product: All Innodisk EM Flash and Dram products

1. 宜鼎國際股份有限公司（以下稱本公司）特此保證此售予貴公司之產品，皆符合歐盟化學品法案(Registration , Evaluation and Authorization of Chemicals : (EC) No 1907/2006 REACH) 以及附錄 XIV 中的限用物質之規定 (http://www.echa.europa.eu/de/candidate-list-table **last updated: 12/01/2017，SVHC's 173)**。

   所提供之產品包含：(1) 產品或產品所使用到的所有原物料；(2)包裝材料；(3)設計、生產及重工過程中所使用到的所有原物料。

   We Innodisk Corporation hereby declare that our products are in compliance with the requirements according to the (EC) No 1907/2006 REACH Regulation and restricted substances in Annex XIV (http://www.echa.europa.eu/de/candidate-list-table **last updated: 12/01/2017，SVHC's 173).**

   Products include： 1) Product and raw material used by the product ; 2) Packaging material ; 3) Raw material used in the process of design, production and rework.

2. 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。

   InnoDisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

立 保 證 書 人 (Guarantor)

Company name 公司名稱： InnoDisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人： Randy Chien 簡川勝

Company Representative Title 公司代表人職稱： Chairman 董事長

Date 日期： 2017 / 02 / 08

CE

VERIFICATION OF COMPLIANCE

This Verification of Compliance is hereby issued to the below named company. The test results of this report relate only to the tested sample identified in this report.

Technical Standard: EMC DIRECTIVE 2014/30/EU (EN55032)

General Information

Applicant: Innodisk Corporation
5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist.,
New Taipei City 22161, Taiwan (R.O.C)

Product Description

EUT Description: mSATA
Brand Name: Innodisk
Model Number: mSATA 3$*#-&
$:Flash type: (S:SLC, I:iSLC, M:MLC, T:3D TLC)
*:Product line: (E:Embedded, G:EverGreen, R:InnoRobust)
#:Product Generation: (empty, 0~9)
&:Product line: (empty, P:Plus)

Measurement Standard

EN 55032: 2012 / AC: 2013
CISPR 32: 2012

Measurement Facilities

Xindian Lab.: ***Compliance Certification Services Inc.***
No.163-1, Jhongsheng Rd., Xindian Dist., New Taipei City, 23151 Taiwan.
Tel: +886-2-22170894 / Fax: +886-2-22171029

This device has been shown to be in compliance with and was tested in accordance with the measurement procedures specified in the Standards & Specifications listed above and as indicated in the measurement report number: T161004D13-E

Sam Hu

Sam Hu / Assistant Manager
Date: October 11, 2016

VERIFICATION OF COMPLIANCE

This Verification of Compliance is hereby issued to the below named company. The test results of this report relate only to the tested sample identified in this report.

Technical Standard: FCC Part 15 Class B
IC ICES-003

General Information

Applicant: Innodisk Corporation
5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist.,
New Taipei City 22161, Taiwan (R.O.C)

Product Description

EUT Description: mSATA
Brand Name: Innodisk
Model Number: mSATA 3$*#-&
$:Flash type: (S:SLC, I:iSLC, M:MLC, T:3D TLC)
*:Product line: (E:Embedded, G:EverGreen, R:InnoRobust)
#:Product Generation: (empty, 0~9)
&:Product line: (empty, P:Plus)

Measurement Facilities

Xindian Lab.: ***Compliance Certification Services Inc.***
No.163-1, Jhongsheng Rd., Xindian Dist., New Taipei City, 23151 Taiwan.
Tel: +886-2-22170894 / Fax: +886-2-22171029

This device has been shown to be in compliance with and was tested in accordance with the measurement procedures specified in the Standards & Specifications listed above and as indicated in the measurement report number: T161004D13-D

Sam Hu

Sam Hu / Assistant Manager
Date: October 11, 2016

MSL Declaration of Conformity

1. Purpose: MSL (Moisture Sensitivity Levels) specification statement for all Innodisk products

2. Scope: For All Innodisk finish goods

3. Responsibilities: QA

4. Reference:

   4.1 JEDEC, S-STD-020

   4.2 JEDEC,J-STD-033

5. Description

   5.1 Innodisk Products Level: All Innodisk products meet MSL Level 1

   5.2 Floor Life Time: Refer following table

	Soak Requirements					
	Floor Life		Standard		Accelerated	
Level	Time	Cond degC/%RH	Time (hrs)	Cond degC/%RH	Time (hrs)	Cond degC/%RH
1	unlimited	<=30/85%	168+5/-0	85/85	n/a	n/a
2	1 year	<=30/60%	168+5/-0	85/60	n/a	n/a
2a	4 weeks	<=30/60%	696+5/-0	30/60	120+1/-0	60/60
3	168 hours	<=30/60%	192+5/-0	30/60	40+1/-0	60/60
4	72 hours	<=30/60%	96+2/-0	30/60	20+0.5/-0	60/60
5	48 hours	<=30/60%	72+2/-0	30/60	15+0.5/-0	60/60
5a	24 hours	<=30/60%	48+2/-0	30/60	10+0.5/-0	60/60
6	TOL	<=30/60%	TOL	30/60	n/a	60/60

Innodisk Corporation
Quality Assurance Div
Manager
Yi Chuan Chen
Date: 2018.09.21